**Type TLRP Series** 



Key Features

Up to 3 Watt at 70°C

12:06, 20:10, and 25:12 Packages Available

Low Inductance <5nH

AEC-Q200 Qualified

Sulfur Resistant unaffected by sulfur environments



TE Connectivity (TE) is pleased to offer these unique AEC-Q200 qualified High Power Metal Strip Resistors for Current Sensing positions. TLRP resistors have a special metal resistive element combined with suitable barrier layers beneath the solder to prolong terminal life. This model is particularly useful for power management along with DC-DC converting and charging applications, as well as adaptors within SWPS applications.

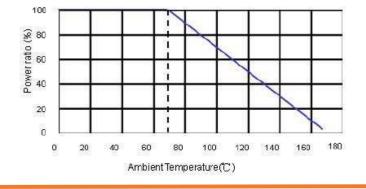
## **Characteristics – Electrical**

Cine	Power Rating	ver Rating Resistance Range (mΩ)					
Size	@ 70°C	±0.5%	±1%	±5%	(PPM/°C)		
		8, 10, 12,	15, 20, 25, 3	0, 33, 40,	±50		
1206	1W	3, 4, 5, 7,	8, 10, 12, 15,	18, 20, 22,	±75		
		25, 30, 33	3, 40, 47, 51,	68, 75, 82,	±100		
		90, 100, 1					
2010	1W	10, 15, 20, 30, 50, 68, 75, 100			+75		
2010	2W	10, 15, 20	175				
		39, 40, 47	7, 18, 20, 22, 2 , 50, 60, 68, 70 0, 120, 150, 18	, 75, 80, 82,	±25		
2512	2W & 3W	1, 2, 3, 4, 5, 6, 7, 8, 9, 10, 12, 15, 18, 20, 22, 25, 27, 30, 33, 35, 39, 40, 47, 50, 51, 56, 60, 68, 70, 75, 80, 82, 90, 91, 100, 120,150, 180, 200, 220			±50 ±75		

Operating Temperature Range: -55 ~ 170°C

Operating Current = V(P/R), Operating Voltage =  $V(P^*R)$ 

## Derating

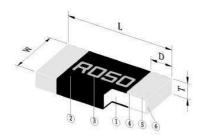


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Dimensions in millimetres unless otherwise specified Dimensions Shown for reference purposes only. Specifications subject to change



# **Construction and Dimensions**



Alloy Plate	(4)	Internal Electrode
@ Overcoat		Barrier Layer
③ Marking	6	Solder Plating

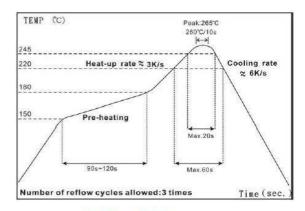
Ту	/pe	Size	L	W	Т	D
			mm	mm	mm	mm
TL	.RP2B	1206	3.15±0.10	1.45±0.10	0.55±0.10	0.55±0.15
TL	.RP2H	2010	5.00±0.10	2.40±0.15	0.60±0.10	0.80±0.20
TL	.RP3A	2512	6.40±0.25	3.20±0.25	0.70±0.20	0.90±0.30

# Marking

**Resistance (4 Digit)** 

Resistance	3mΩ	10mΩ	22mΩ	100mΩ
Codes	R003	R010	R022	R100

## **Solder Profile (Reflow)**



IR Reflow Soldering (1) Time of IR reflow soldering at maximum temperature point 260°C : 10s

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## **Environmental Characteristics**

ItemRequirementTest MethodTemperature Coefficient of Resistance (T.C.R.)As Spec.IEC60115-1 4.8 +25°C ~125°C, 25°C is the reference temperatureShort Time Overload±1.0%IEC60115-1 4.13 JIS-C-5201-1 4.13 5*rated power for 5 secondsInsulation Resistance≥10GIEC60115-1 4.6 JIS-C-5201-1 4.13 100V DC for 1 minuteEndurance±1.0%IEC60115-1 4.25 JIS-C-5201-1 4.13 100V DC for 1 minuteEndurance±1.0%IEC60115-1 4.25 JIS-C-5201-1 4.25.1 70±2°C, rated power for 1000 with 1.5 hrs "ON" and 0.5 hrMIL-STD-202 Method 108 Condition D Steady State TA= at derated power.	) hrs
Resistance (T.C.R.) JIS-C-5201-1 4.8   +25°C ~125°C, 25°C is the reference temperature   Short Time Overload ±1.0%   IEC60115-1 4.13   JIS-C-5201-1 4.13   JIS-C-5201-1 4.13   5*rated power for 5 seconds   Insulation Resistance   ≥10G   IEC60115-1 4.6   JIS-C-5201-1 4.13   100V DC for 1 minute   Endurance   ±1.0%   IEC60115-1 4.25   JIS-C-5201-1 4.25.1   70±2°C, rated power for 1000   with 1.5 hrs "ON" and 0.5 hr   MIL-STD-202 Method 108   Condition D Steady State TA=	) hrs
+25°C ~125°C, 25°C is the reference temperature   Short Time Overload ±1.0%   IEC60115-1 4.13   JIS-C-5201-1 4.13   5*rated power for 5 seconds   Insulation Resistance   ≥10G   IEC60115-1 4.6   JIS-C-5201-1 4.13   100V DC for 1 minute   Endurance   ±1.0%   IEC60115-1 4.25   JIS-C-5201-1 4.25.1   70±2°C, rated power for 1000   with 1.5 hrs "ON" and 0.5 hr   MIL-STD-202 Method 108   Condition D Steady State TA=	) hrs
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Indurance   ±1.0%   IEC60115-1 4.25     JIS-C-5201-1 4.25.1   70±2°C, rated power for 1000     with 1.5 hrs "ON" and 0.5 hr   MIL-STD-202 Method 108     Condition D Steady State TA=	
Endurance   ±1.0%   IEC60115-1 4.25     JIS-C-5201-1 4.25.1   70±2°C, rated power for 1000     with 1.5 hrs "ON" and 0.5 hr   MIL-STD-202 Method 108     Condition D Steady State TA=	
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with 1.5 hrs "ON" and 0.5 hr MIL-STD-202 Method 108 Condition D Steady State TA=	
MIL-STD-202 Method 108 Condition D Steady State TA=	UFF
Condition D Steady State TA=	
at derated power.	:125°C
Measurement at 24±4 hours	after
test conclusion.	
Biased Humidity ±1.0% MIL-STD-202 Method 103	
1000 hrs 85°C/85%RH 10% of	ī
operating power	
Dry Heat ±1.0% IEC60115-1 4.23.2	
JIS-C-5201-1 4.23.2	
MIL-STD-202 Method 108	
at +170°C for 1000 hrs	
Resistance to Solvents No visible damage on MIL-STD-202 Method 215	
appearance and Note: Add Aqueous wash che	mical
marking OKEM Clean or equivalent.	
Do not use banned solvents.	
Mechanical Shock ±1.0% MIL-STD-202 Method 213	
Wave Form: Tolerance for ha	If sine
shock pulse.	
Peak value is 100g's. Normal	
duration(D) is 6.	
Vibration ±1.0% MIL-STD-202 Method 204	
5g's for 20 min., 12 cycles ead	ch of
3 orientations.	
Note: Use 8"X5" PCB .031" th	ick 7
secure points on one long sid	e and
2 secure points at corners of	
opposite sides. Parts mounte	d
within 2" from any secure po	
Test from 10-2000 Hz.	
ESD ±1.0% AEC-Q200-002	
Human body model, 2KV. (DO	2 =
Direct Contact Discharge)	
Flammability V-0 UL-94	
50W (20 mm) Vertical Burnin	
Test. Electrical test not requir	g

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Item	Requirement	Test Method
Flame Retardance	The following	AEC-Q200-001
	phenomena cannot	Assemble the sample on the test
	occur during the	board, perform functional test
	experiment:	before flame retardant test to
	(1)A flame over 3.0	ensure no damage to the sample.
	seconds duration.	The test environment is 22±5 °C
	(2)An explosion.	still air, from 9.0 to 32.0 VDC
	(3)A temperature	(current clamped up to 500A),
	above 350°C	increase the voltages at the rate of
	sustained for over 10	1.0 VDC per hour until the end of
	seconds	the experiment.
Bending Strength	±1.0%	JIS-C-5201-1 4.33
		IEC-60115-1 4.33
		AEC-Q200-005
		Bending width 2mm once for 5
		seconds
Terminal Strength (SMD)	Not broken	AEC-Q200-006
		Force of 1.8kg for 60 seconds.
Solderability	95% min. coverage	JIS-C-5201-1 4.17
		IEC-60115-1 4.17
		J-STD-002
		245±5°C for 3seconds
Resistance to Soldering	±0.5%	JIS-C-5201-1 4.18
Heat		IEC-60115-1 4.18
		MIL-STD-202 Method 210
		260±5°C for 10 seconds
Rapid Change of	±1.0%	JIS-C-5201-1 4.19
Temperature		IEC-60115-1 4.19
		-55°C to +155°C, 5 cycles
Temperature Cycling	±1.0%	JESD22 Method JA-104
		1000 cycles (-55°C to +125°C,
		Dwell 30 minutes, transition time
		within 1 minute). Measurement at
		24±4 hours after test conclusion.
Low Temperature Storage	±1.0%	IEC60115-1 4.23.4
		JIS-C-5201-1 4.23.4
		at -55°C for 2hrs

RCWV (Rated Continuous Working Voltage)=  $v(P^*R)$  or Max. Operating Voltage whichever is lower.

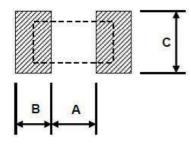
### Storage Temperature: 15~28°C; Humidity < 80%RH

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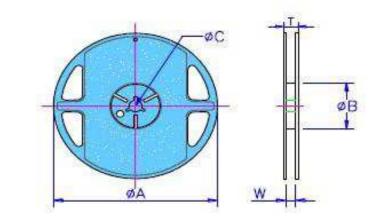
# **Recommended Land Pattern**



Size	A (mm)	B (mm)	C (mm)				
1206	1.50	1.40	1.70				
2010	3.60	1.40	2.50±0.2				
2512	4.00	2.00	3.50				
*FR4 copper board, 100μm of copperpad thickness							

# Packaging

# Reel Specifications & Packaging Quantity



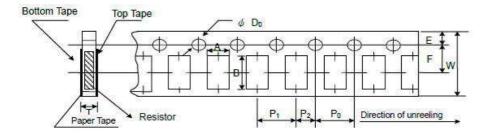
Size	Resistance (mΩ	Tape / Qty	Tape width	Reel Dia.	ØA (mm) ±1.5	ØB (mm)	ØC (mm )	W (mm)	T (mm )
1206	3~40	Paper / 5K	8mm			60 <sup>+1-0</sup>	13.0 ±0.2	9.0±0.5	12.5 ±0.5
2010	10~100	Embossed / 4K	12mm	7	178.5	60 <sup>+1-0</sup>	13.0 ±0.5	13.0 ±0.5	15.5 ±0.5
2512	4~200	Embossed / 4K	12mm	inch	1/8.5	60±1.0	13.0	13.0±1.	15.5
2512	3	Embossed / 2K	12mm			00±1.0	±0.5	0	±0.5

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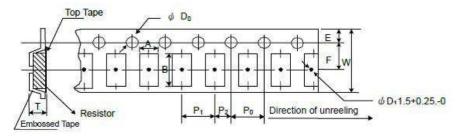


### Paper Tape Specification



А	В	W	E	F	Po	P <sub>1</sub>	P <sub>2</sub>	ØD₀	Т
(mm)	(mm)	(mm)	(mm)	(mm)	(mm)	(mm)	(mm)	(mm)	(mm)
1.90±	3.50±	8.0±	1.75±	3.50±	4.00±	4.00±	2.00±	1.50	0.85±
0.10	0.20	0.20	0.10	0.05	0.10	0.05	0.05	+0.1,-0	0.10

### **Embossed Plastic Tape Specification**



	А	В	W	E	F	Po	P <sub>1</sub>	P <sub>2</sub>	ØD。	Т	
	(mm)	(mm)	(mm)	(mm)	(mm)	(mm)	(mm)	(mm)	(mm)	(mm)	
2010	2.80	5.5	12.0	0.75	5.5	4.00	4.00	2.00	1.5 +0.1	1.20+0	
2010	±0.10	±0.10	±0.30	±0.10	±0.5	±0.10	±0.10	±0.05	-0	1.20+0	
2512	2 501	6.70±	12.01	1 751		4 001	4.00±	2.00±	1.50 +0.1	1.20+0	
2512	3.50± 0.10	6.70± 0.10	12.0± 0.30	1.75± 0.10	5.5± 0.05	4.00± 0.10	4.00± 0.10	2.00± 0.05	1.50 +0.1 -0	1.45±	
3mΩ	0.10	0.10	0.30	0.10	0.05	0.10	0.10	0.05	-0	0.2	

### **How To Order**

TLRP	2B	10	E	R008	F	TD
Common Part	Size	*Power Rating	**TCR (PPM/°C)	Resistance Code	Tolerance	Packaging
TLRP – Ultra Low Ohm Metal Strip Resistor	2B – 1206 2H - 2010 3A – 2512	1.0 = 10 2.0 = 20 3.0 = 30	C = ±25 D = ±50 W = ±75 E = ±100	R003 - 3mΩ R020 - 20mΩ R10 – 0.1Ω (100mΩ)	D = ±0.5% F = ±1% J = ±5%	TDG = 2000/Reel (2512 3mΩ) TE = 4000/Reel (2512) TD = 5000/Reel (1206)

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单击下面可查看定价,库存,交付和生命周期等信息

>>TE Connectivity(泰科)